









CED02N9

900V Δ 5.3Ω Δ 2A Δ Si MOSFET

SILICON Si MOSFET ▲ THT type

N-channel enhancement mode

UL94V-0 rated flame retardant epoxy

TO251 (E-PAK) package

Super high dense cell density for extremely low R_{DS(ON)} **High power and current handling capability**

MAXIMUM RATINGS

Parameter (T _C = 25°C, unless otherwise noted)		Characteristics
Drain-Source Voltage	V _{DS}	900V
Gate-Source Voltage	V _{GS}	±30V
Continuous Drain Current at T _C = 25°C	I D	2A
Pulsed Drain Current Note 1	I _{DM}	8A
Maximum Power Dissipation at T _C = 25°C	P _D	75W
Power Dissipation Derating above 25°C	ΔP _D	0.5W/°C
Operating and Storage Temperature Range	T _J , T _{STG}	-55°C to +175°C

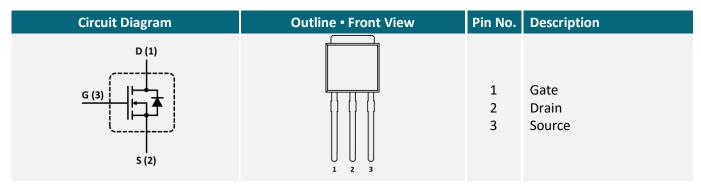
THERMAL CHARACTERISTICS

Parameter	Symbol	Limit
Thermal Resistance, Junction-to-Case	R _{TH_JC}	2°C/W
Thermal Resistance, Junction-to-Ambient	R _{TH_JA}	50°C/W

APPLICATIONS

Base Station Power	Battery Chargers	LED Lighting	Power Adapters	SMPS
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PIN DESCRIPTION





ELECTRICAL CHARACTERISTICS \blacktriangle T_C = 25°C, unless otherwise noted

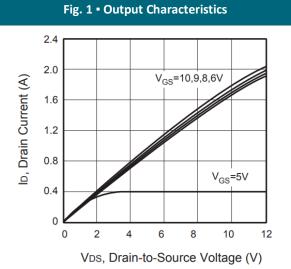
Item	Condition	Symbol	Min.	Тур.	Max.	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	$V_{GS} = 0V$, $I_D = 250\mu A$	BV_{DSS}	900			V
Zero Gate Voltage Drain Current	$V_{DS} = 900V, V_{GS} = 0V$	I _{DSS}			25	μΑ
Gate Body Leakage Current, Forward	$V_{GS} = 30V, V_{DS} = 0V$	I _{GSSF}			100	nA
Gate Body Leakage Current, Reverse	$V_{GS} = -30V, V_{DS} = 0V$	I_{GSSR}			-100	nA
On Characteristics Note 2						
Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 250 \mu A$	$V_{GS(th)}$	2		4	V
Static Drain-Source On-Resistance	$V_{GS} = 10V$, $I_D = 1A$	R _{DS(ON)}		5.3	6.8	Ω
Dynamic Characteristics Note 3						
Input Capacitance	$V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$	C _{ISS}		705		pF
Output Capacitance	$V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$	Coss		85		pF
Reverse Transfer Capacitance	$V_{DS} = 25V$, $V_{GS} = 0V$, $f = 1MHz$	C_{RSS}		20		pF
Switching Characteristics Note 3						
Turn-On Delay Time	$V_{DD} = 450V$, $V_{GS} = 10V$, $I_D = 2A$, $R_{G(ext)} = 25\Omega$	$t_{D(ON)}$		27		ns
Turn-On Rise Time	V_{DD} = 450V, V_{GS} = 10V, I_D = 2A, $R_{G(ext)}$ = 25 Ω	t _R		23		ns
Turn-Off Delay Time	V_{DD} = 450V, V_{GS} = 10V, I_{D} = 2A, $R_{G(ext)}$ = 25 Ω	t _{D(OFF)}		47		ns
Turn-Off Fall Time	V_{DD} = 450V, V_{GS} = 10V, I_D = 2A, $R_{G(ext)}$ = 25 Ω	t _F		21		ns
Total Gate Charge	$V_{DS} = 720V$, $V_{GS} = 10V$, $I_D = 2A$	Q_{G}		22		nC
Gate Source Charge	$V_{DS} = 720V$, $V_{GS} = 10V$, $I_D = 2A$	Q_{GS}		4		nC
Gate Drain Charge	$V_{DS} = 720V$, $V_{GS} = 10V$, $I_D = 2A$	Q_{GD}		12		nC
Drain-Source Diode Characteristics and Maximum Ratings						
Drain-Source Diode Forward Current		Is			2	Α
Drain-Source Diode Forward Voltage Note 2	$V_{GS} = 0V$, $I_S = 2A$	V_{SD}			1.2	V

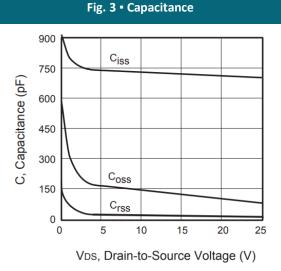
Notes

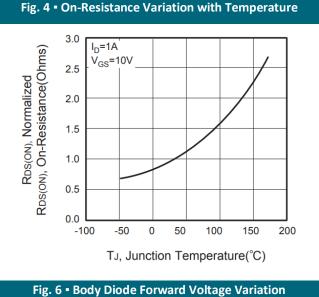
- 1: Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2: Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 3: Guaranteed by design, not subject to production testing.

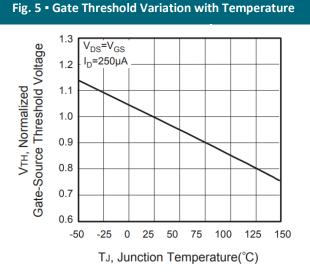


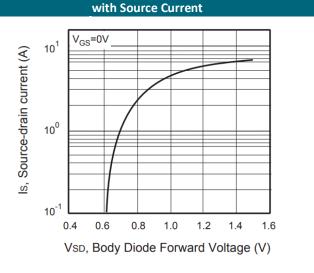
REFERENCE DATA A TYPICAL DEVICE PERFORMANCE











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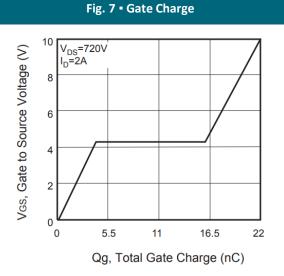


Fig. 8 • Maximum Safe Operating Area

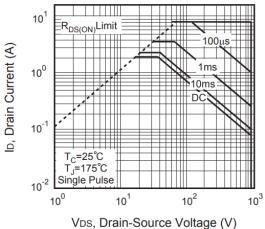
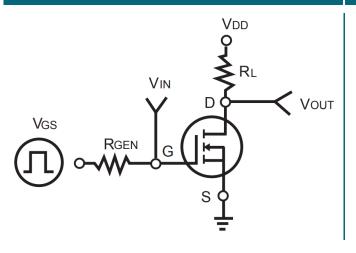


Fig. 9 • Switching Test Circuit

Fig. 10 • Switching Waveforms



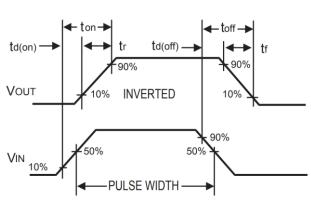
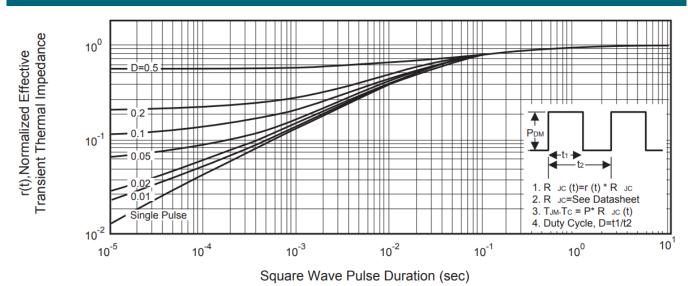


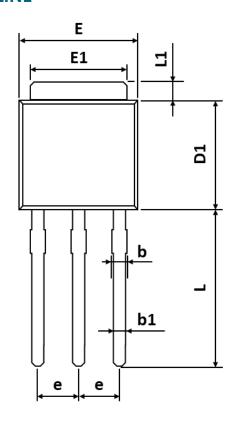
Fig. 11 - Normalized Thermal Transient Impedance Curve

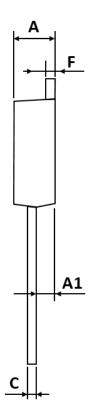


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PACKAGE OUTLINE





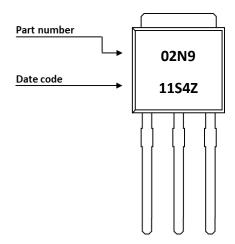
Sym	Millimeters (Min.)	Millimeters (Typ.)	Millimeters (Max.)
Α	2.180	-	2.400
A1	0.860	-	1.500
b	0.700	-	0.960
b1	0.700	-	0.860
С	0.400	-	0.610
D1	5.400	-	6.630
Е	6.050	-	7.010
E1	4.950	-	5.460
е	1.980	-	2.590
F	0.400	-	0.890
L	8.500	-	9.650
L1	0.500	-	1.800

ORDERING INFORMATION

Part Number	Package	Packing	Tube Qty.	Inner Box Qty.	Outer Box Qty.
CED02N9	TO251 (E-PAK)	Tube	80pcs	4,000pcs	16,000pcs

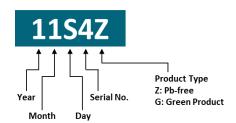


PART MARKING



DATE CODE

Example: 11S4Z



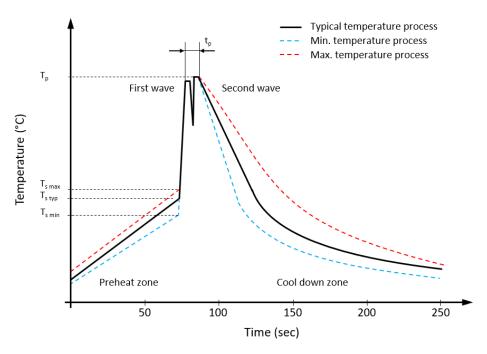


Coding list for "Day"





RECOMMENDED WAVE SOLDERING PROFILE A THT PACKAGE



Classification wave soldering profile ▲ Refer to EN 61760-1: 2006

Profile Features		Value ▲ Sn-Pb Assembly	Value ▲ Pb-free Assembly
Preheat temperature min.	T_{smin}	100 °C	100 °C
Preheat temperature typical	T _{s typ}	120 °C	120 °C
Preheat temperature max.	T_{smax}	130 °C	130 °C
Preheat time t_s from T_{smin} to T_{smax}	ts	70 seconds	70 seconds
Peak temperature	T_p	235 °C to 260 °C	245 °C to 260 °C
Time of actual peak temperature	t _p	Max. 10 seconds Max. 5 second each wave	Max. 10 seconds Max. 5 second each wave
Ramp-down date min.		~ 2 °C/second	~ 2 °C/second
Ramp-down rate typical		~ 3.5 °C/second	~ 3.5 °C/second
Ramp-down rate max.		~ 5 °C/second	~ 5 °C/second
Time 25°C to 25°C		4 minutes	4 minutes



REVISION TABLE

Revision	Date	Status	Notes
001	30/09/2022	Initial release	Initial publication

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